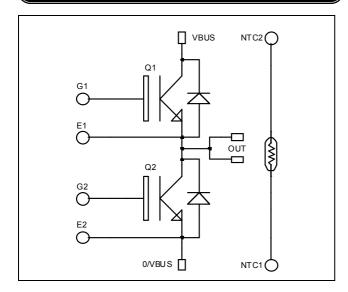


Phase leg Fast Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 1200V$$

 $I_{C} = 100A$ @ $Tc = 80$ °C



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- High level of integration
- Internal thermistor for temperature monitoring



G2 🛍 E2 🛭 O/VBUS OUT E2 🛚 NTC2 8 G2 N NTC1 0

Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- **RoHS** Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	140	
I_{C}	Continuous Conector Current	$T_C = 80$ °C	100	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	200	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Maximum Power Dissipation	$T_C = 25$ °C	480	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	200A @ 1100V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V	Collector Emitter Saturation Voltage		$T_j = 25$ °C	1.4	1.7	2.1	V
$V_{CE(sat)}$				2.0		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		7200		
C_{oes}	Output Capacitance	$V_{CE} = 25V$		400		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		300		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)	260		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		30		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 100A$		420		ns
T_{f}	Fall Time	$R_G = 3.9\Omega$		70		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°	C)	290		
T_{r}	Rise Time	$V_{GE} = \pm 15V$		50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 100A$		520		ns
T_{f}	Fall Time	$R_G = 3.9\Omega$		90		
Eon	Turn on Energy	$V_{GE} = \pm 15V \ V_{Bus} = 600V$ $T_j = 125^{\circ}$	C	10		mJ
E_{off}	Turn off Energy	$\begin{bmatrix} I_C = 100A \\ R_G = 3.9\Omega \end{bmatrix}$ $T_j = 125^\circ$	C	10		1110

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_i = 25$ °C $T_i = 125$ °C			250 500	μА
I_{F}	DC Forward Current		$T_c = 80^{\circ}C$		100	300	A
V	V_F Diode Forward Voltage $ I_F = 100A $ $V_{GE} = 0V $	$I_F = 100A$	$T_i = 25^{\circ}C$		1.6	2.1	V
v _F		$T_{i} = 125^{\circ}C$		1.6		·	
t_{rr}	Reverse Recovery Time	$T_{j} = 25^{\circ}C$ $T_{j} = 125^{\circ}C$	$T_j = 25^{\circ}C$		170		ns
CII			$T_j = 125$ °C		280		
0	Reverse Recovery Charge	$\begin{aligned} I_F &= 100A \\ V_R &= 600V \\ di/dt &= 2000A/\mu s \end{aligned}$	$T_j = 25$ °C		9		μС
Q_{rr}	Reverse Recovery Charge		$T_{i} = 125^{\circ}C$		18		μС
Г	D D En		$T_j = 25^{\circ}C$		5		ma I
E_{r}	Reverse Recovery Energy		$T_i = 125$ °C		9		mJ

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 $Temperature\ sensor\ NTC\ (see\ application\ note\ APT0406\ on\ www.microsemi.com\ for\ more\ information).$

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

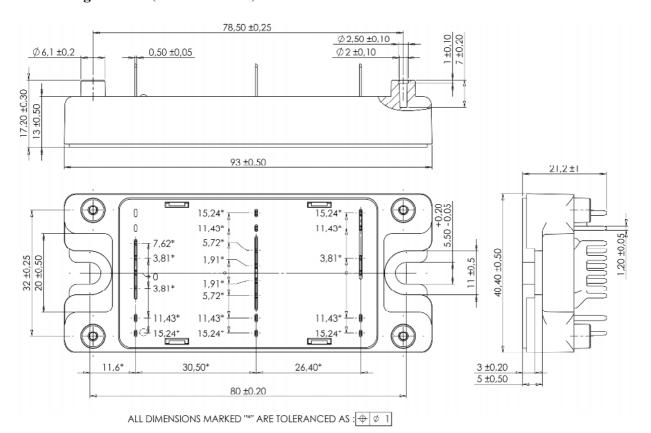
$$R_T = \frac{R_{25}}{\exp \left[\frac{1}{R_{25/85}} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.26	°C/W
			Diode			0.48	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range		-40		150		
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

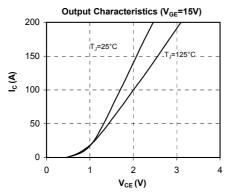
SP4 Package outline (dimensions in mm)

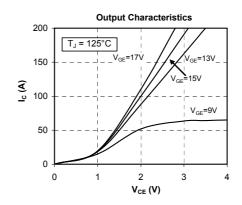


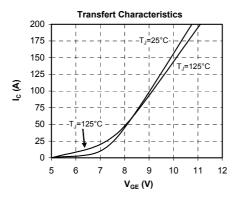
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

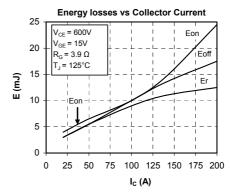


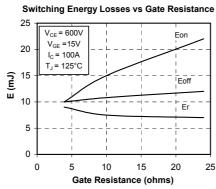
Typical Performance Curve

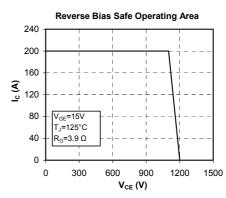


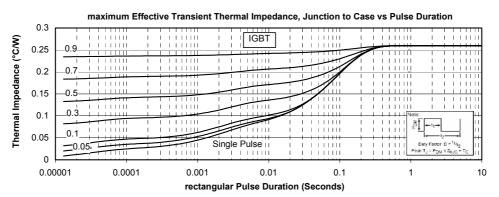




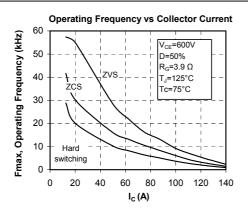


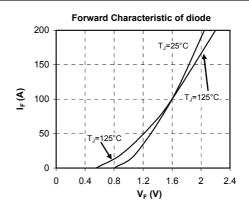


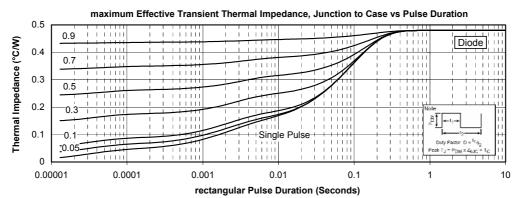














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